

## High Efficiency LED, ø 5 mm Tinted Non-Diffused Package

Color	Type	Technology	Angle of Half Intensity $\pm\varphi$
High efficiency red	TLHR52../TLHR62..	GaAsP on GaP	14°
Yellow	TLHY52../TLHY62..	GaAsP on GaP	14°
Green	TLHG52../TLHG62..	GaP on GaP	14°

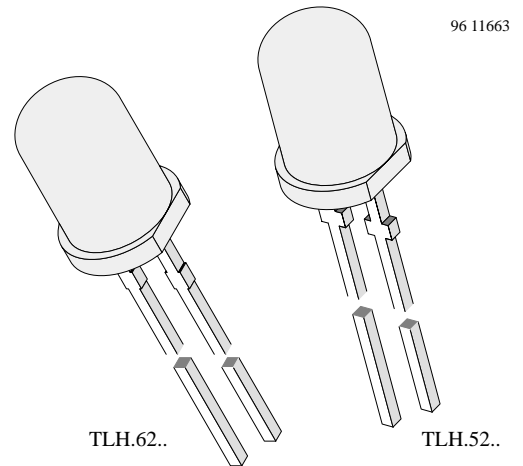
### Description

The TLH.52.. and 62.. series was developed for standard applications like general indicating and lighting purposes.

It is housed in a 5 mm tinted non-diffused plastic package. The small viewing angle of these devices provides a high brightness.

Several selection types with different luminous intensities are offered. All LEDs are categorized in luminous intensity groups. The green and yellow LEDs are categorized additionally in wavelength groups.

That allows users to assemble LEDs with uniform appearance.



### Features

- Choice of three bright colors
- Standard T-1¾ package
- Small mechanical tolerances
- Suitable for DC and high peak current
- Small viewing angle
- Luminous intensity categorized
- Yellow and green color categorized
- TLH.52.. with stand-offs
- TLH.62.. without stand-offs

### Applications

Status lights  
 OFF / ON indicator  
 Background illumination  
 Readout lights  
 Maintenance lights  
 Legend light

### Absolute Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

TLHR52../TLHR62.. , TLHY52../TLHY62.. , TLHG52../TLHG62.. ,

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
DC forward current	$T_{amb} \leq 65^{\circ}\text{C}$	$I_F$	30	mA
Surge forward current	$t_p \leq 10 \mu\text{s}$	$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 65^{\circ}\text{C}$	$P_V$	100	mW
Junction temperature		$T_j$	100	$^{\circ}\text{C}$
Operating temperature range		$T_{amb}$	-20 to +100	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	-55 to +100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5 \text{ s}$ , 2 mm from body	$T_{sd}$	260	$^{\circ}\text{C}$
Thermal resistance junction/ambient		$R_{thJA}$	350	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

High efficiency red (TLHR52../TLHR62..)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10 \text{ mA}$	TLHR5200/6200	$I_V$	10	20		mcd
		TLHR5201/6201	$I_V$	16	30		mcd
		TLHR5205/6205	$I_V$	25	40		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	612		625	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		635		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 14$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$		$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{V\text{Min.}}/I_{V\text{Max.}} \leq 0.5$

Yellow (TLHY52../TLHY62..)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10 \text{ mA}$	TLHY5200/6200	$I_V$	10	30		mcd
		TLHY5201/6201	$I_V$	16	40		mcd
		TLHY5205/6205	$I_V$	25	50		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	581		594	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		585		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 14$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$		$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{V\text{Min.}}/I_{V\text{Max.}} \leq 0.5$



**Green (TLHG52../TLHG62..)**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10 \text{ mA}$	TLHG5200/6200	$I_V$	16	30		mcd
		TLHG5201/6201	$I_V$	25	40		mcd
		TLHG5205/6205	$I_V$	40	50		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	562		575	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		565		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 14$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{V\text{Min.}}/I_{V\text{Max.}} \leq 0.5$

**Typical Characteristics ( $T_{\text{amb}} = 25^\circ\text{C}$ , unless otherwise specified)**

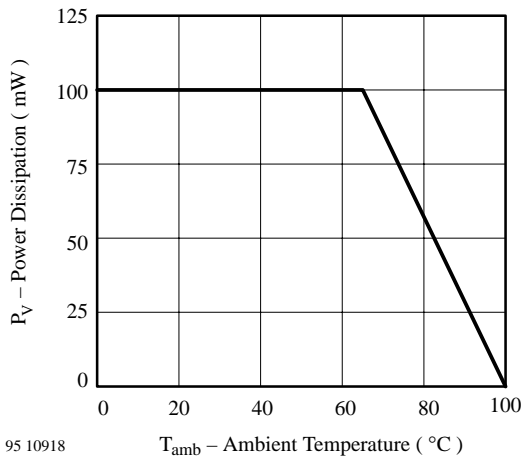


Figure 1. Power Dissipation vs. Ambient Temperature

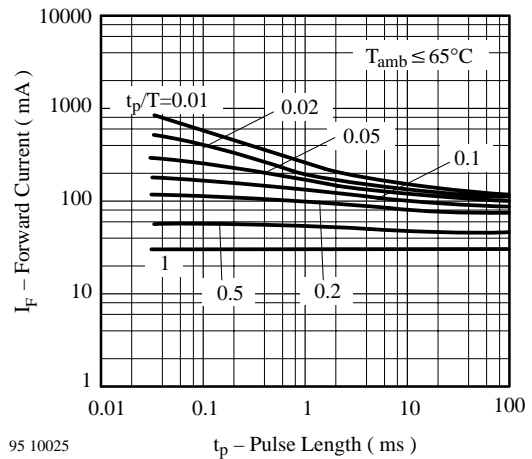


Figure 3. Forward Current vs. Pulse Length

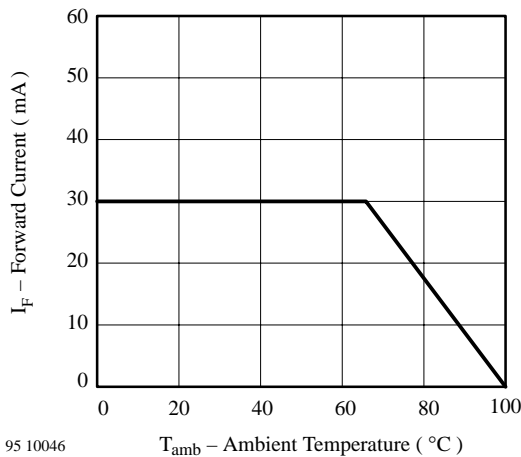


Figure 2. Forward Current vs. Ambient Temperature

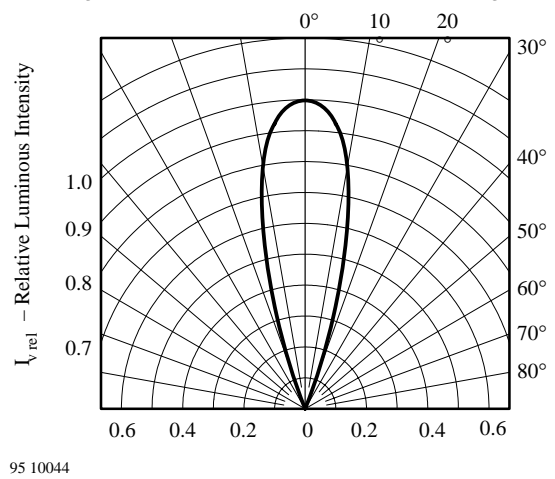
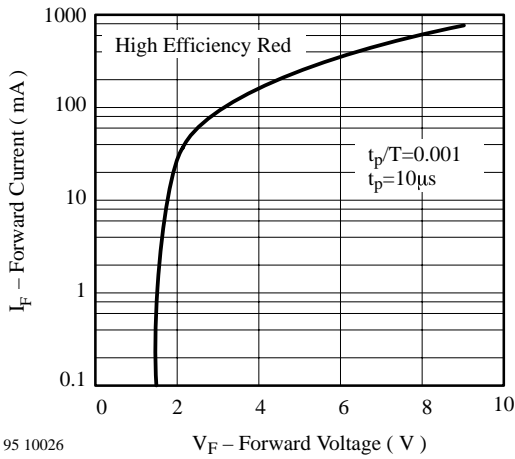
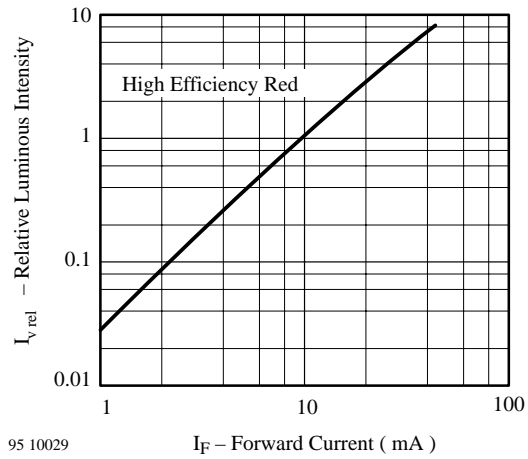


Figure 4. Rel. Luminous Intensity vs. Angular Displacement



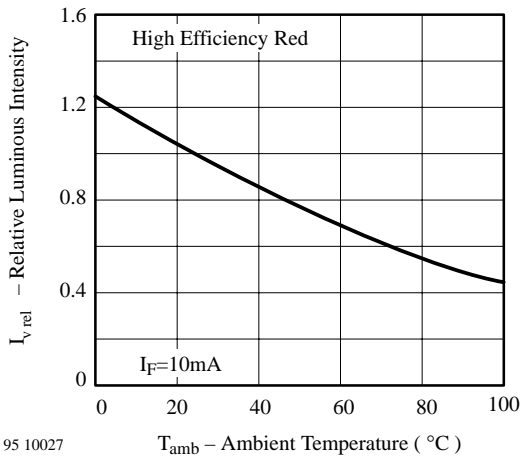
95 10026

Figure 5. Forward Current vs. Forward Voltage



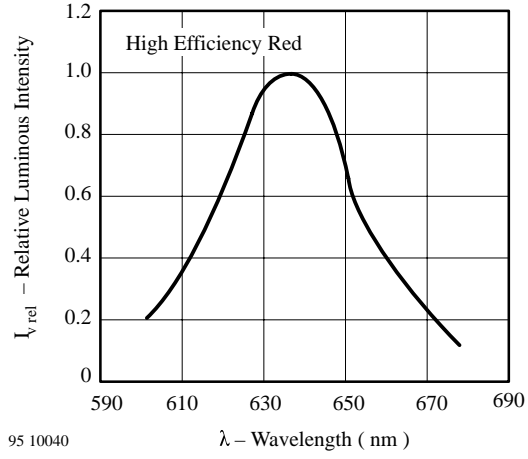
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Figure 8. Relative Luminous Intensity vs. Forward Current



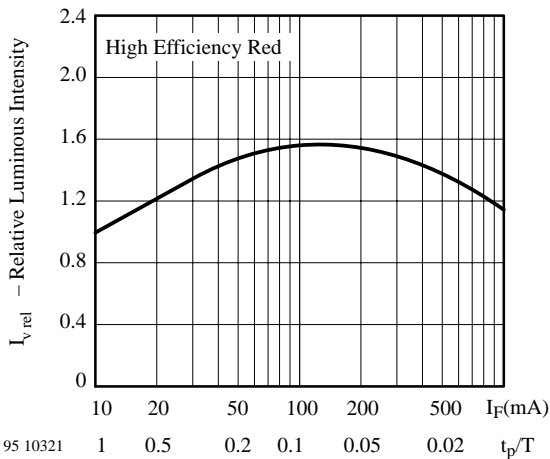
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Figure 6. Rel. Luminous Intensity vs. Ambient Temperature



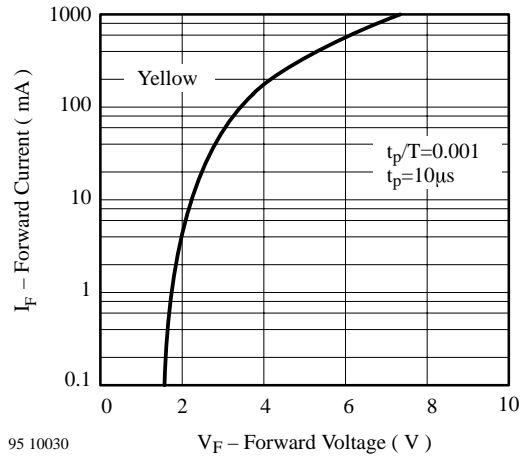
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Figure 9. Relative Luminous Intensity vs. Wavelength



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Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle



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Figure 10. Forward Current vs. Forward Voltage

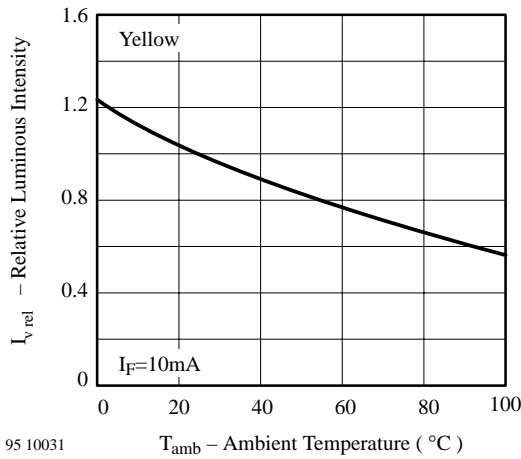


Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

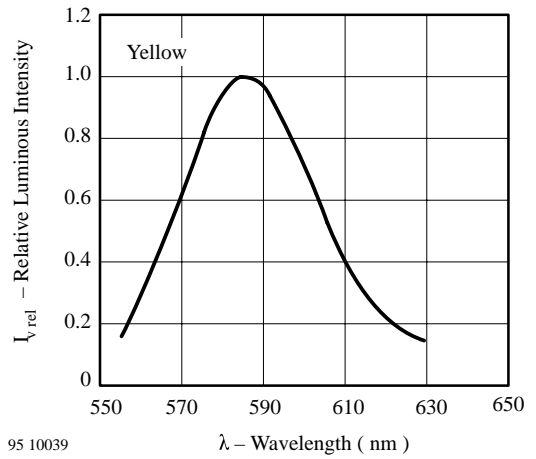


Figure 14. Relative Luminous Intensity vs. Wavelength

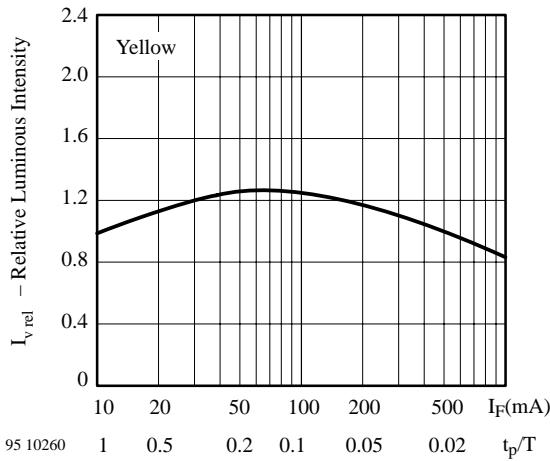


Figure 12. Rel. Luminous Intensity vs. Forw. Current/Duty Cycle

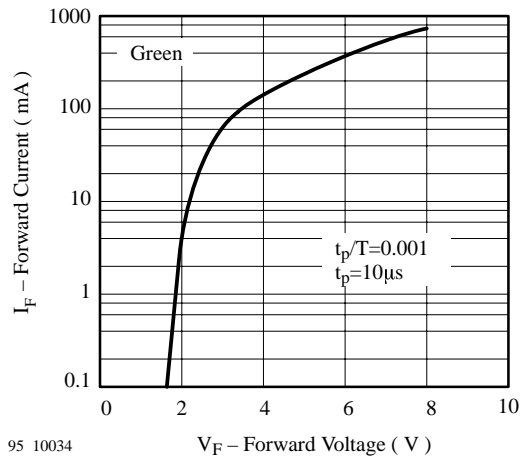


Figure 15. Rel. Luminous Intensity vs. Ambient Temperature

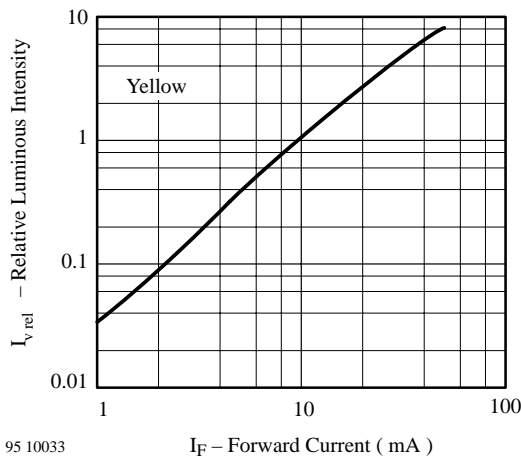


Figure 13. Relative Luminous Intensity vs. Forward Current

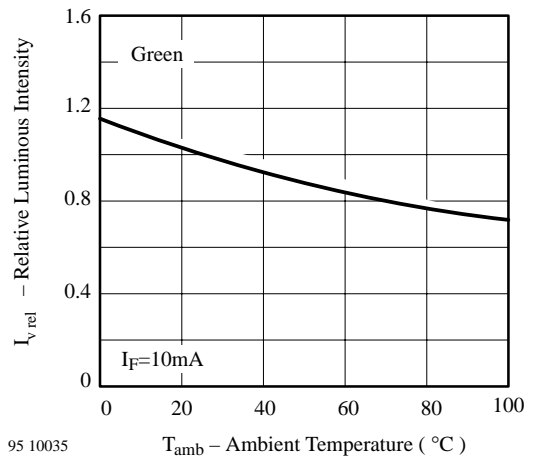


Figure 16. Rel. Luminous Intensity vs. Ambient Temperature

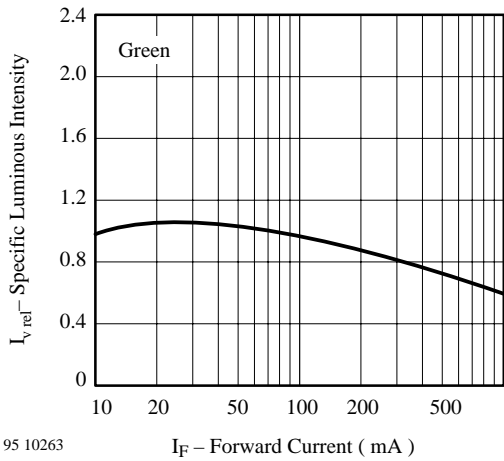


Figure 17. Specific Luminous Intensity vs. Forward Current

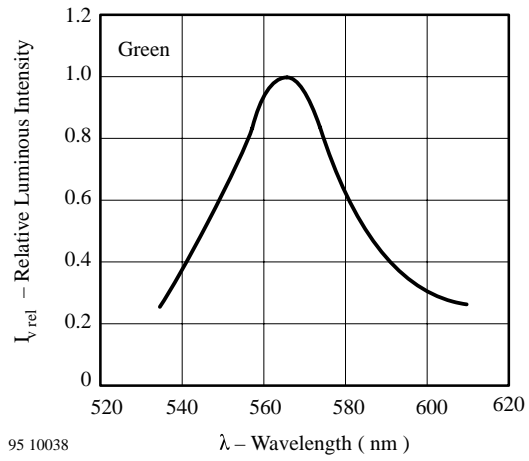


Figure 19. Relative Luminous Intensity vs. Wavelength

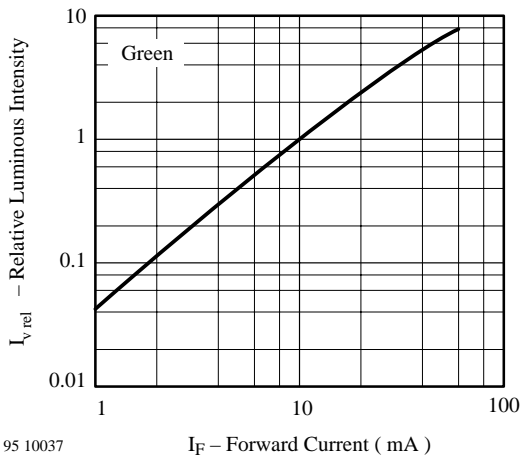


Figure 18. Relative Luminous Intensity vs. Forward Current



**Ozone Depleting Substances Policy Statement**

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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